

# Dielectric properties of Y-doped $\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$ ceramics

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Y-doped  $\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$  (Y-BST) ceramics ( $x = 0.1, 0.2, 0.4, 0.7$ ) were prepared by solid-state reaction and sintered at 1250, 1300, 1350, and 1400 °C for 1 h. The effect of strontium solution and sintering temperature on the structure, microstructure and dielectric properties of Y-BST was investigated. SEM investigations revealed a grain size decreasing with the Sr content increase. The temperature dependence of permittivity showed decrease in phase transition temperature with higher Sr content. Enhancing sintering temperature is effective to increase the grain size and improve the microstructure porosity. The XRD patterns of all Y-doped  $\text{Ba}_{0.3}\text{Sr}_{0.7}\text{TiO}_3$  ceramics indicated that the crystal cell parameters increase when temperature increased. However, the (002) and (200) peaks of Y-doped  $\text{Ba}_{0.3}\text{Sr}_{0.7}\text{TiO}_3$  split when sintering temperature was increased to 1400 °C, which makes the structure of the specimen transit to tetragonal ( $a = 3.9857 \text{ \AA}$  and  $c = 4.018 \text{ \AA}$ ) from cubic. It may be attributed to the fact that  $\text{Y}^{3+}$  ion can occupy both A site and B site of  $\text{Ba}_{0.3}\text{Sr}_{0.7}\text{TiO}_3$  sintered at 1400 °C, which leads to the large different internal stress in individual grains, and then induces the structure change. The temperature coefficient of capacitance (TCC) value of the Y-doped  $\text{Ba}_{0.3}\text{Sr}_{0.7}\text{TiO}_3$  sintered at 1400 °C changed little within  $\pm 6\%$  over a temperature range from 10 to 130 °C.

Keywords: Y-doped,  $\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$  ceramics, dielectric properties.

## 1. Introduction

In recent years, materials with a high  $\varepsilon_r$ , dielectric constant and lead-free compositions have attracted much interest for environment-friendly applications [1, 2]. The most experimentally and theoretically investigated materials are perovskite-based  $\text{SrTiO}_3$ ,  $\text{BaTiO}_3$  and the  $\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$  alloys, because they are prototype ferroelectrics and are used extensively in the capacitor industry [3].

Barium strontium titanate ( $\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$ ) is a solid solution family composed of barium titanate and strontium titanate with its Curie temperature covering a wide range of temperature.  $\text{SrTiO}_3$  in a bulk form changes from a simple cubic perovskite structure to a tetragonal perovskite structure near 105 K and retains that phase down

to absolute zero [4]. BaTiO<sub>3</sub> ceramic is a typical ferroelectric material with the Curie temperature around 130 °C. BaTiO<sub>3</sub>-based ferroelectric has been considered to be an important material for various applications, such as dynamic random access memory (DRAM) [5], multilayer ceramic capacitors (MLCCs) [6], phased array antennas [7], microwave devices [8], as well as in sensors and positive temperature coefficient (PTC) thermistor [9].

In BaTiO<sub>3</sub> the Curie point can be shifted to lower temperature by the substitution of Sr<sup>2+</sup> for Ba<sup>2+</sup>, or Sn<sup>4+</sup> or Zr<sup>4+</sup> for Ti<sup>4+</sup> and to higher temperatures by the substitution of Pb<sup>2+</sup> for Ba<sup>2+</sup> [10]. The main purpose of adding Sr<sup>2+</sup> into BST is to shift the Curie temperature towards room temperature and make BST a paraelectric material at room temperature offering high dielectric constant, low leakage current and low dielectric loss against frequency.

Previous studies on the dielectric properties of Ba<sub>1-x</sub>Sr<sub>x</sub>TiO<sub>3</sub> ceramic solid solutions have shown that the compositions with  $x < 0.2$  exhibited normal ferroelectric behaviour, while a relaxor characteristic was observed in the SrTiO<sub>3</sub> rich region ( $x \geq 0.2$ ) [11, 12]. In addition, the dependence of the Curie temperature on the grain size has been reported [13]. However, knowledge of the effect of sintering temperature on the dielectric properties is still limited. In this paper, we discuss the effect of Sr<sup>2+</sup> substitution and sintering condition on the dielectric properties of Ba<sub>1-x</sub>Sr<sub>x</sub>TiO<sub>3</sub> samples doped with 0.2 at.% Y<sub>2</sub>O<sub>3</sub> (Y-BST). YUANLIANG LI *et al.* [14] reported that the proper additive amount of Y<sup>3+</sup> can accelerate growth of the grains and improve the dielectric constant of Ba<sub>0.62</sub>Sr<sub>0.38</sub>TiO<sub>3</sub> ceramics. Furthermore, the authors have reported that donor doping, such as Y<sup>3+</sup> for BaTiO<sub>3</sub>-based ceramics, is an excellent method for improving the resistance degradation in highly accelerated life test (HALT) for Ni electrode MLCCs [15]. Therefore, in our experiment, the BST samples were doped with 0.2 at.% Y<sub>2</sub>O<sub>3</sub>.

## 2. Experiment

Y<sub>2</sub>O<sub>3</sub> doped Ba<sub>1-x</sub>Sr<sub>x</sub>TiO<sub>3</sub> ceramics with molar formula ( $x = 0.1, 0.2, 0.4, 0.7$ ) were synthesized by a solid state reaction method. The starting materials were carbonate (BaCO<sub>3</sub>, SrCO<sub>3</sub>) and oxide (TiO<sub>2</sub>, Y<sub>2</sub>O<sub>3</sub>) powders of purity higher than 99%. The raw materials were mixed in stoichiometric proportions, ball-milled in water for 24 h, and dried in an oven. The powders were finely pulverized, precalcined and then formed into disks under a uniaxial pressure of 174 MPa. The disc-shaped pellets were sintered in air at 1250, 1300, 1350, and 1400 °C for 1 h, and furnace cooled. Silver paste was applied to both sides of the samples (1 mm thick and 10 mm diameter) and then the samples were fired at 150 °C for 1 h.

The crystalline structure of the Y-BST ceramics was analyzed by X-ray diffraction (XRD) analysis using Cu K $\alpha$  radiation. The microstructure and the elemental distribution were examined by scanning electron microscopy (SEM S-2500) and energy-dispersive X-ray (EDX) using a scanning electron microscope equipped with an X-ray energy-dispersive EDX spectrometer. Measurements of the temperature

dependence of the dielectric constant and dielectric loss at 1 kHz were performed on a capacitance measurement system (HP4294A), which includes a self-acting LCR bridge in the  $-30$  to  $130$  °C temperature range.

### 3. Results and discussion

Figure 1 is the SEM images of Y-BST samples sintered at  $1300$  °C. It has been found that with Sr content increasing, the grain size of all specimens becomes smaller. It should be noted that the  $Sr^{2+}$  ionic radius ( $1.16$  Å) is smaller than  $Ba^{2+}$  ionic radius ( $1.35$  Å), so the substitution of  $Sr^{2+}$  for  $Ba^{2+}$  will make the lattice volume smaller, which suppresses the grain growth.

Figures 2a and 2b show the variation of dielectric constant  $\epsilon_r$  and dielectric loss  $\tan \delta$ , respectively, with temperature for different samples at 1 kHz frequency performed in the  $-30$  °C to  $130$  °C temperature range. The decrease in the phase transition temperature with the Sr concentration increase can be observed for all samples. The ferroelectric transition temperature of Y-BST with  $x = 0.1, 0.2, 0.4$  is  $110, 80$ , and  $10$  °C, respectively. In addition, the dielectric loss ( $x = 0.1, 0.2, 0.4$ ) also shows a peak at the transition temperature, which indicates a well-defined phase

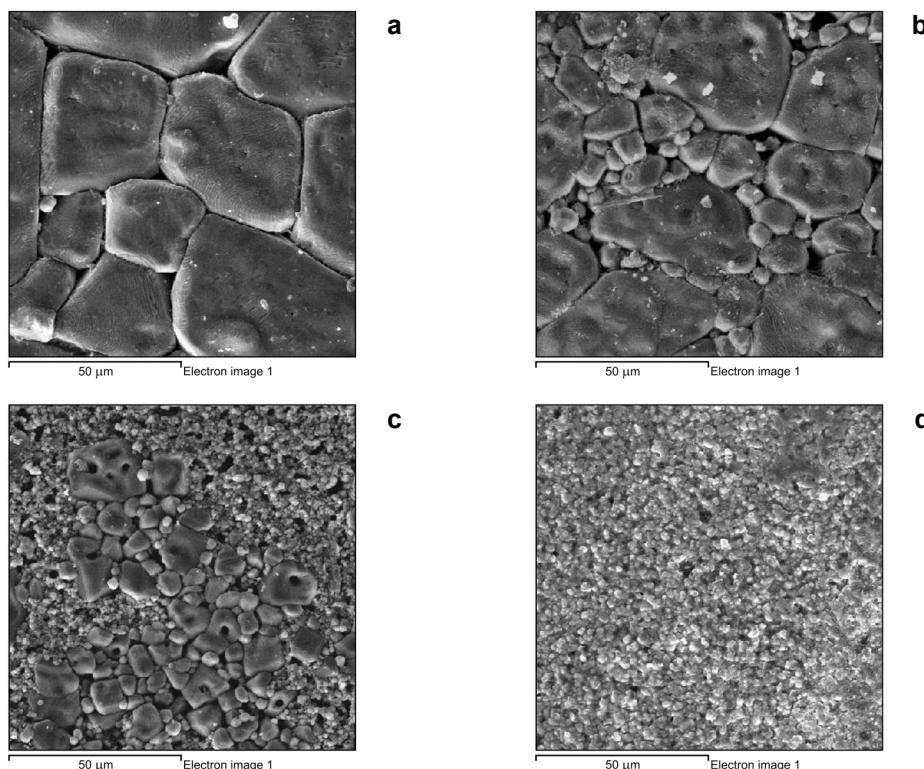


Fig. 1. SEM micrographs of Y-doped  $Ba_{1-x}Sr_xTiO_3$  samples sintered at  $1300$  °C for 1 h;  $x = 0.1$  (a),  $x = 0.2$  (b),  $x = 0.4$  (c), and  $x = 0.7$  (d).

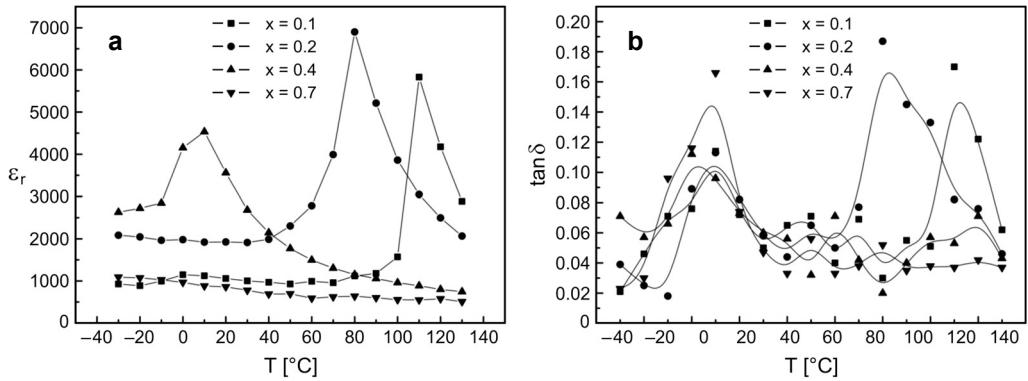


Fig. 2. Temperature variation of the dielectric constant (**a**) and dielectric loss (**b**) of Y-doped  $\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$  samples measured at 1 kHz.

transition. The dielectric constant maximum increases firstly and then decreases with Sr concentration increasing, which is due to the porosity of the structure and smaller grains seen in Fig. 1. Further, a closer look at the dielectric constant–temperature ( $\epsilon_r-T$ ) plots reveals a broadening of the transition peaks with higher Sr content, which can be attributed to inhomogeneous morphology and more small grains. Thanks to dielectric measurements of perovskite ferroelectrics, the diffuse phase transition can be induced by factors such as decreasing grain size and local disorder mode through the local strain [16, 17].

Figure 3 shows the XRD patterns of Y-doped  $\text{Ba}_{0.3}\text{Sr}_{0.7}\text{TiO}_3$  specimens sintered at 1250, 1300, 1350, and 1400 °C for 1 h. The XRD patterns of all samples showed a single perovskite phase, which confirmed the fact that  $\text{Y}^{3+}$  ion can be almost incorporated into the perovskite lattice of BST. Moreover, the samples sintered at 1250, 1300, and 1350 °C are mainly composed of the cubic structures with lattice parameters of  $a = 3.9224 \text{ \AA}$ ,  $3.9373 \text{ \AA}$ , and  $3.9784 \text{ \AA}$ , respectively. However, it is interesting that

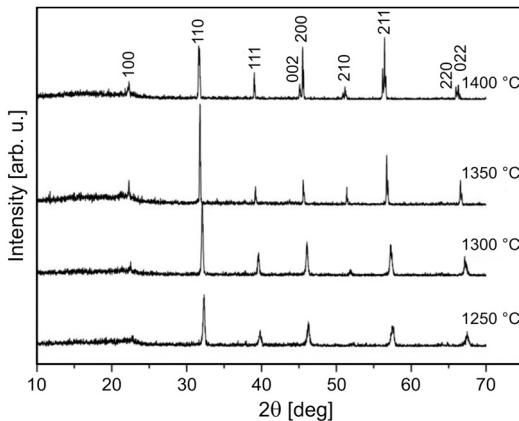


Fig. 3. XRD patterns of Y-doped  $\text{Ba}_{0.3}\text{Sr}_{0.7}\text{TiO}_3$  specimens sintered at different temperatures for 1 h.

when sintering temperature increases to 1400 °C, the (002) and (200) peaks split, which implies that the structure of the specimen transiting to tetragonal ( $a = 3.9857 \text{ \AA}$  and  $c = 4.018 \text{ \AA}$ ) from cubic.

SEM images (Fig. 4) show that enhancing sintering temperature is effective to increase the grain size and microstructure density. Especially, the sample sintered at 1400 °C exhibits an exaggerated grain growth, which shows the same abnormal characteristic in the XRD analysis. This may be relative to the A or B site of  $Y^{3+}$  substitution, which is explained below.

In the  $ABO_3$  perovskite structure, dopant cations can enter substitutionally into two different lattice sites – the smaller, octahedrally coordinated B-sites, or the larger, dodecahedrally coordinated A-sites, mainly depending on their ionic radii. The large ionic radius group prefers to incorporate into Ba sites, while the small ionic radius group usually incorporates into Ti sites. The intermediate ionic radius group can occupy one of the two sites depending upon the A/B (Ba/Ti) ratio, and thermodynamic conditions, such as the partial pressure of oxygen in the sintering atmosphere [18]. The rare-earths ions (as well as  $Y^{3+}$ ) have ionic radii between the  $Ba^{2+}$  (A-sites, coordination 12) and  $Ti^{4+}$  (B-sites, coordination 6) and can occupy both cationic lattice sites in the  $BaTiO_3$  structure [18, 19].

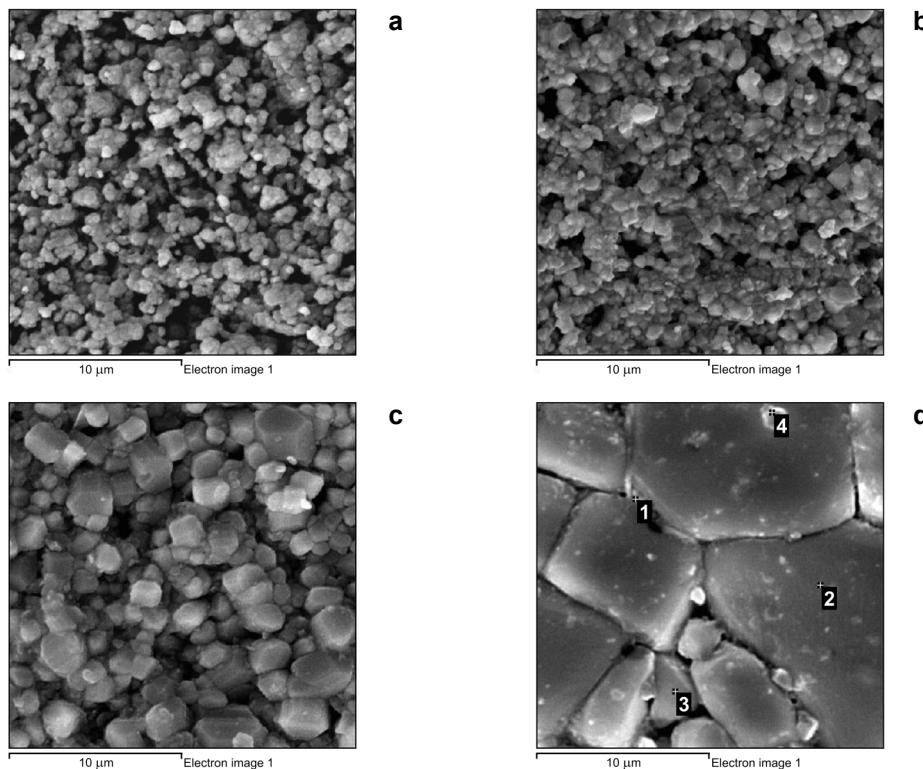
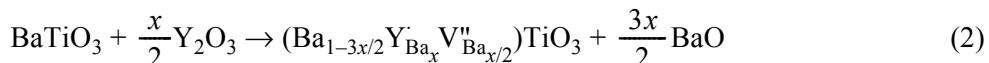
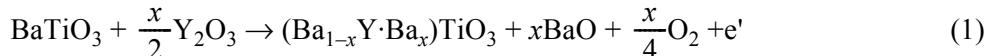


Fig. 4. SEM images of Y-doped  $Ba_{0.3}Sr_{0.7}TiO_3$  specimens sintered at different temperatures for 1 h.

MAKOVEC *et al.* [20] reported that the incorporation site of  $\text{Y}^{3+}$  ion in the  $\text{BaTiO}_3$  perovskite structure depended mainly on the starting composition. In the  $\text{TiO}_2$ -rich samples, a relatively low concentration (below  $\sim 1.5$  mol%) of  $\text{Y}^{3+}$  is incorporated preferentially at the  $\text{Ba}^{2+}$  lattice sites at  $1400^\circ\text{C}$ . In  $\text{BaO}$ -rich samples, a high solid solubility ( $\sim 15$  mol%) of  $\text{Y}^{3+}$  at the  $\text{Ti}^{4+}$  lattice sites appeared at  $1500^\circ\text{C}$ .

The  $\text{Y}^{3+}$  ion incorporated at the  $\text{Ba}^{2+}$  site would act as a donor, and under equilibrium conditions this extra donor charge is compensated for by ionized Ba and electronically according to the following equations (A-site substitution):



Furthermore, the  $\text{Y}^{3+}$  ion incorporated at the  $\text{Ti}^{4+}$  site acts as an acceptor, and the extra charge is compensated for by ionized oxygen vacancies according to the following equation (B-site substitution):

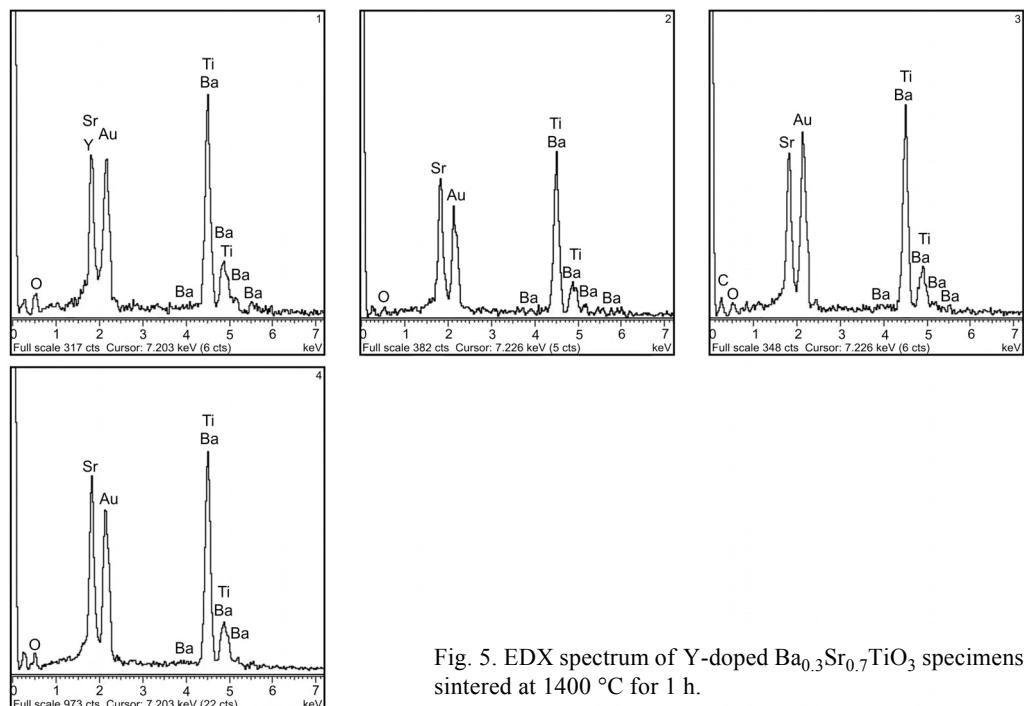
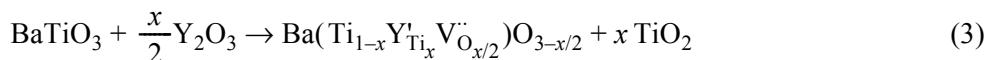


Fig. 5. EDX spectrum of Y-doped  $\text{Ba}_{0.3}\text{Sr}_{0.7}\text{TiO}_3$  specimens sintered at  $1400^\circ\text{C}$  for 1 h.

Table. The relative elements atomic proportion.

| Selected points    | 1    | 2    | 3    | 4    | Theoretic value |
|--------------------|------|------|------|------|-----------------|
| (Ba+Sr)/Ti(atomic) | 1.08 | 1.05 | 0.92 | 1.02 | 1               |

Therefore, if Ba-rich or Ti-rich minor phases were identified,  $Y^{3+}$  occupation site could be determined. Figure 5 shows the minor phase identifications using EDX for Y-BST fired at 1400 °C. The qualitative EDX spectra show the presence of main elements (Ba, Sr, Ti) and minor addition elements (Y) but also of an artefact related to the presence of Au used for the specimen preparation in the selected region. The relative elements analysis is listed in the Table.

SHIGEKI SATO *et al.* [21] reported that Y occupied perovskite A-site under  $A/B \leq 1.00$ , and perovskite B-site under  $A/B > 1$  using a minor phase identification. In our experiment, the theoretic value of  $A/B$  is 1. Therefore, the Y should preferentially occupy the A site. From Fig. 4, it is clear that the BST samples sintered at 1250–1300 °C show the homogeneous grains, which may be attributed to the  $Y^{3+}$  incorporated only at the A site resulting in the similar internal stress state which existed in all grains. Also for this reason, the  $Ba_{0.3}Sr_{0.7}TiO_3$  can retain stable cubic structure in the 1250–1300 °C sintering temperature.

However, when the sintering temperature reaches 1400 °C, the  $Y^{3+}$  ion may occupy both A and B sites. From the Table, it is obvious that the A/B ratio of the large grains (point 2 and 4) is larger than 1, which indicates that the  $Y^{3+}$  ion incorporated at Ti sites creates the oxygen vacancies. While the A/B ratio of the small grain (point 3) is smaller than 1, it implies that the  $Y^{3+}$  ion incorporated into Ba sites creates the Ba and Sr cation vacancies. In the grain boundary regions (point 1) simultaneously exist the A site elements (Ba + Sr) and the B site element (Ti), and this also proves that the  $Y^{3+}$  ion may occupy both cationic lattice sites in the BST specimen sintered at 1400 °C.

ARMSTRONG and BUCHANAN [22] reported that internal stress existed between cores and shells and attributed this internal stress to the thermal expansion mismatch between cores and shells in individual grains. In the Y-doped BST Specimen sintered at 1400 °C, the  $Y^{3+}$  ion occupies both cationic lattice sites, and this will lead to the distinctly different stress state between the A-site substitution region and B-site substitution region, which gives rise to the abrupt structure change from cubic to tetragonal phase observed from XRD results.

Figures 6a and 6b show the temperature dependence of the dielectric constants and TCC (temperature coefficient of capacitance) curves of the Y-doped BST system, respectively. From the dielectric measurements at low frequency (1 kHz) performed over the –30 to 130 °C temperature range, the dielectric constant increases with the sintering temperature increasing. Moreover, the sample sintered at 1400 °C exhibits the highest dielectric constant and a wide transition peak from ferroelectric to paraelectric state, which is corresponding to the XRD analysis. HENNINGS *et al.* [23] proposed that internal stresses in the microstructure were the major cause of the observed distribution of the Curie temperature. Therefore, the sample sintered at

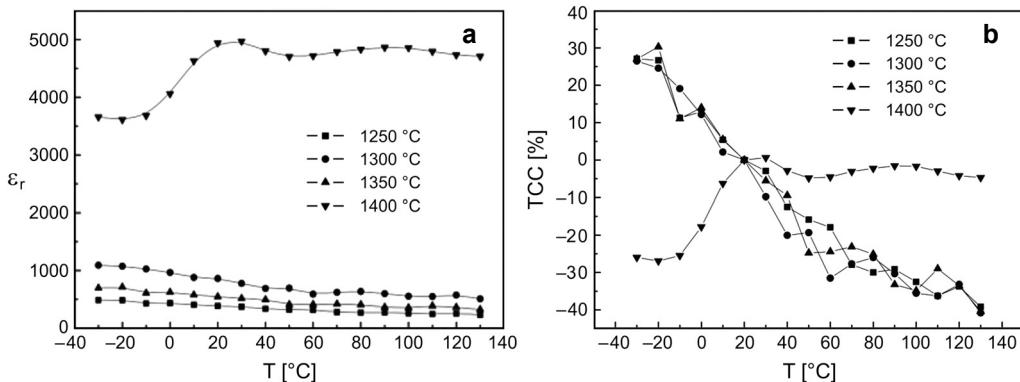


Fig. 6. Temperature variation of the dielectric constant of Y-doped Ba<sub>0.3</sub>Sr<sub>0.7</sub>TiO<sub>3</sub> specimens at different sintering temperatures for 1 h, measured at 1 kHz (a). TCC (%) curves of Y-doped Ba<sub>0.3</sub>Sr<sub>0.7</sub>TiO<sub>3</sub> as a function of different sintering temperatures for 1 h (b).

1400 °C exhibits a diffuse phase transition and this is compatible with the above analytical result.

Figure 6b shows the TCC curves of Y-doped BST as a function of sintering temperature. From the TCC curves, it can be observed that the TCC values of the samples sintered at 1250–1350 °C change much during the test temperature range. In contrast, the specimen sintered at 1400 °C has a more stable capacitance variation. The dielectric constants change within ±6% of the room temperature value over the temperature range from 10 to 130 °C.

#### 4. Conclusions

In summary, the Y-doped Ba<sub>1-x</sub>Sr<sub>x</sub>TiO<sub>3</sub> ceramics were prepared by solid-state reaction and by sintering at 1250, 1300, 1350, and 1400 °C, with strontium content  $x = 0.1, 0.2, 0.4, 0.7$ . The increasing concentration of Sr has the following effects: *i*) decreases the grain size; *ii*) decreases considerably the ferroelectric transition temperature; and *iii*) increases the diffuse phase transition. The grain size and the microstructure density were found to increase with higher sintering temperature. The Ba<sub>0.3</sub>Sr<sub>0.7</sub>TiO<sub>3</sub> specimen sintered at 1400 °C shows exaggerated grain growth and abrupt structure change from cubic to tetragonal, which may be due to the Y<sup>3+</sup> ions incorporated into both sites of BST resulting in a large stress distinction. The Ba<sub>0.3</sub>Sr<sub>0.7</sub>TiO<sub>3</sub> sintered at 1400 °C presents a more stable TCC value within ±6% over the test temperature.

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